

MPS
2316
STATIC READ
ONLY MEMORY
(2048x8)

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DESCRIPTION

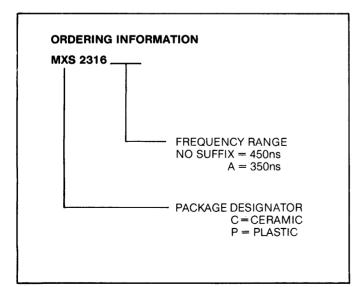
The 2316 high performance read only memory is organized 2048 words by 8 bits with access times of less than 350 ns. This ROM is designed to be compatible with all microprocessor and similar applications where high performance, large bit storage and simple interfacing are important design considerations.

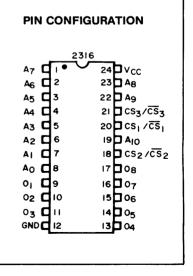
The 2316 operates totally asynchronously. No clock input is required. The three programmable chip select inputs allow eight 16K ROMS to be OR-tied without external decoding.

Designed to replace two 2708 8K EPROMS, the 2316 can eliminate the need to redesign printed circuit boards for volume mask programmed ROMS after prototyping with EPROMS.

- 400mV Noise Immunity on Inputs
- 2048 x 8 Bit Organization
- Single +5 Volt Supply
- Access Time 450 ns, 350 ns
- Totally Static Operation
- TTL Compatible

- Three-State Outputs for Wire-OR Expansion
- Three Programmable Chip Selects
- Pin Compatible with 2716 EPROM
- Replacement for two 2708s
- 2708/2716 EPROMS Accepted as Program Data Inputs







ABSOLUTE MAXIMUM RATINGS

Ambient Temperature under Bias Storage Temperature -65°C to +70°C -65°C to +150°C Supply Voltage to Ground Potential Applied Output Voltage -0.5V to +7.0V Applied Input Voltage -0.5V to +7.0V Power Dissipation 1.0W

COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

D. C. CHARACTERISTICS ($T_A = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$, unless otherwise specified)

Symbol	Parameter	Min.	Max.	Units	Test Conditions
ICC1	Power Supply Current		100	mA	$V_{IN} = V_{CC}, V_0 = Open, T_A = 0^{\circ}C$
ICC2	Power Supply Current		95	mΑ	$V_{IN} = V_{CC}, V_0 = Open, T_A = 25^{\circ}C$
10	Output Leakage Current		10	μΑ	Chip Deselected, $V_0 = 0$ to V_{CC}
11	Input Load Current		10	μA	$V_{CC} = Max. V_{IN} = 0 \text{ to } V_{CC}$
VOL	Output Low Voltage		0.4	Volts	$V_{CC} = Min. I_{OL} = 2.1 mA$
Voн	Output High Voltage	2.4		Volts	V_{CC} = Min. I_{OH} = -400μ A
VIL	Input Low Voltage	-0.5	0.8	Volts	See Note 1
ViH	Input High Voltage	2.0	VCC+1	Volts	

A. C. CHARACTERISTICS (TA = 0°C to $+70^{\circ}$ C, $V_{CC} = 5.0V \pm 5\%$, unless otherwise specified)

	Parameter	2316		2316A			
Symbol		Min.	Max.	Min.	Max.	Units	Test Conditions
tACC	Address Access Time		450		350	ns	
tco	Chip Select Delay		200		200	ns	
tDF	Chip Deselect Delay		175		175	ns	See Note 2
tОН	Previous Data Valid After Address Change Delay	40		40		ns	

CAPACITANCE $(T_A = 25^{\circ}C, f = 1.0 \text{MHz}, \text{See Note 3})$

Symbol	Parameter	Min.	Max.	Units	Test Conditions
CIN	Input Capacitance		8	рF	All Pins except Pin under
COUT	Output Capacitance		10	pF	Test Tied to AC Ground

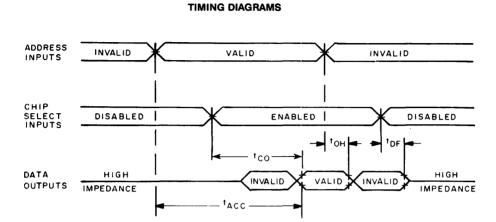
Note 1: Input levels that swing more negative than -0.5V will be clamped and may cause damage to the device.

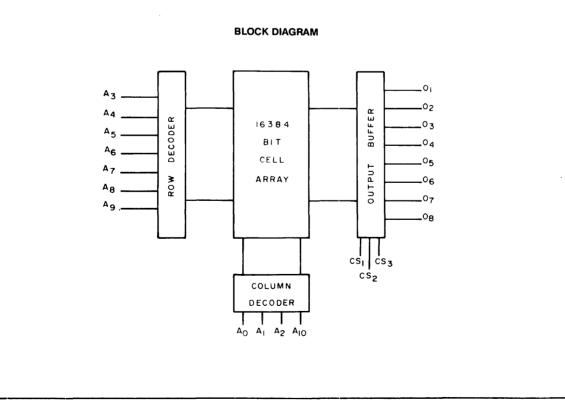
Note 2: Loading 1 TTL + 100 pF, input transition time: 20 ns

Timing measurement levels: input 1.5V, output 0.8V and 2.0V.

Note 3: This parameter is periodically sampled and is not 100% tested.

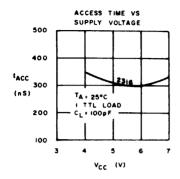


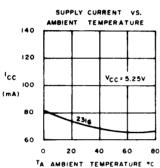


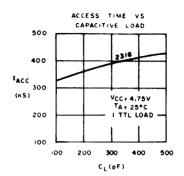


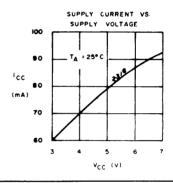


TYPICAL CHARACTERISTICS

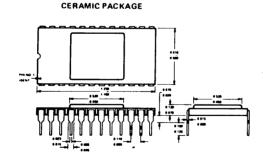


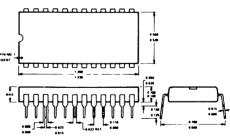






PACKAGING DIAGRAM





MOLDED PACKAGE

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